Texture dependent strain rate sensitivity of ultrafine-grained aluminum films

Ehsan Izadi, Jagannathan Rajagopalan *

Department of Mechanical and Aerospace Engineering, School for Engineering of Matter, Transport and Energy, Arizona State University, Tempe 85287, USA

ABSTRACT

We investigated the strain rate sensitivity (SRS) of freestanding ultrafine-grained aluminum films with similar thickness (~240 nm) and mean grain size (~275 nm) but highly dissimilar texture. For (110) textured bicrystalline films, flow stress increased by 14% (m = 0.017) as the strain rate was varied from ~7 × 10⁻⁶/s to 5 × 10⁻³/s. In contrast, for non-textured films the flow stress increased by more than 90% (m = 0.103) over a similar strain rate range. The drastic difference in SRS can be explained by texture-induced changes in deformation mechanisms of the films, as revealed by in situ TEM straining experiments.

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Ultrafine-grained (UFG) and nanocrystalline (NC) metals exhibit a number of appealing mechanical properties such as high strength and increased wear resistance [1]. Metallic thin films with UFG/NC microstructures are employed in numerous applications including structural coatings, interconnects in semiconductor devices, in thermomechanical applications and as structural and electrode components in micro-electro-mechanical systems (MEMS) [2–4]. In many of these applications, and particularly in MEMS, the metallic films may be subjected to a wide range of loading rates. For instance, in MEMS based high frequency oscillators or thermomechanical switches the deformation times can vary from microseconds to milliseconds. It is known that the mechanical response of UFG/NC metal films depends on the rate at which they are deformed. Therefore, in order to gain reliable operation of MEMS, the mechanical behavior of metal films over various loading rates needs to be understood [4,5]. Strain rate sensitivity (SRS) studies of thin metal films have typically focused on mechanical behavior at rates between 10⁻⁶/s and 10⁻³/s [6–9], but more recently a wider range of strain rates [4,10–12] have been explored. SRS studies of UFG/NC metals have been mainly directed towards elucidating the effect of mean grain size on their rate dependent mechanical response. These studies have shown that across a wide range of metals SRS increases and activation volume decreases [6,7,10,13] as the grain size becomes finer.

But in addition to the mean grain size, texture is also known to significantly influence the deformation behavior of UFG/NC metal films. Torre et al. have shown that differences in texture lead to variation in the yield stress and ultimate tensile stress of NC nickel foils [14]. Similarly, experiments on nanoscale aluminum (Al) films with similar mean grain size and thickness but different textures have revealed significant differences in flow stress and Bauschinger effect [15,16]. However, the effect of texture on the SRS of metallic films has not been systematically investigated so far.

In this study, we investigated the SRS of two sets of nanoscale Al films with nearly identical thickness (~240 nm) and mean grain size (275–285 nm), but substantially different textures. Our results unambiguously show that SRS of UFG Al films is strongly dependent on film texture. Films with a strong (110) out-of-plane texture and composed only of two in-plane grain variants (bicrystalline films) show significantly smaller SRS compared to films with a random orientation of grains (non-textured films). The flow stress of the bicrystalline films increased by 14% when the strain rate was increased from ~7 × 10⁻⁶/s to 5 × 10⁻³/s. In contrast, the flow stress of non-textured films increased by over 90% over a similar strain rate range.

The bicrystalline Al film (labeled as textured film) and the non-textured Al film were synthesized by carefully controlling the deposition conditions. To obtain the textured film, the native silicon dioxide layer on a (001) oriented silicon (Si) wafer was removed through hydrofluoric acid etching and the wafer was immediately transferred to the sputtering chamber to avoid regrowth of the oxide layer. Al was then deposited on the bare Si wafer using DC magnetron sputtering,
which resulted in heteroepitaxial growth with the following relationship: Al(110)//Si(001), Al[001]/Si[110] and Al(110)//Si[110] [17]. Thus, this film consists of just two grain families with (110) out-of-plane texture which are rotated 90° in plane with respect to each other. The non-textured film was obtained using a similar process except that it was sputter deposited on a Si(001) wafer with the native silicon dioxide layer intact. The oxide layer disrupts the epitaxial growth of Al, leading to a film with random orientation of grains. Both the textured film and non-textured film were deposited to a thickness of ~240 nm at 5.5 nm/min. The chamber base pressure during deposition of the textured and non-textured film was 8 × 10⁻⁸ Torr and 3 × 10⁻⁷ Torr, respectively.

The microstructure of the films was examined through transmission electron microscopy (TEM) and X-ray diffraction (XRD). Based on plan-view TEM images, the textured Al film had a mean grain size of 275 nm and the non-textured film had a mean grain size of 285 nm (Fig. 1). The images also indicated a columnar grain structure with one grain traversing the thickness of the film. To perform the experiments, dog-bone shaped freestanding samples were co-fabricated with MEMS based tensile testing devices (Fig. 2a) using microfabrication techniques outlined in [18]. The MEMS devices have built-in gauges to track the sample deformation. A piezoelectric actuator (Physik Instrumente) was used to load the devices and a CMOS camera (Thor Labs) was used to acquire images of the gauges during the experiments. A custom MATLAB™ program, which tracks prescribed features across a series of images using cross-correlation techniques, was used to measure the displacement of the gauges and thus the sample strain.

A miniature s-beam load cell (Futek), arranged in series with the MEMS device, measured the total force ($F_{\text{tot}}$) on the device (Fig. 2b). As evident from the equivalent mechanical model of the device, $F_{\text{tot}} = F_S + F_{U} + F_A$, where $F_S$ is the force on the sample and $F_{U}$ and $F_A$ are the force on the U-beams and the Alignment beams, respectively. The combined stiffness ($K$) of the U-beams and Alignment beams was measured in a separate experiment after the sample had fractured. $K$ multiplied by the displacement ($x$) gives $F_{U} + F_A$, from which $F_S$ and thus the stress on the sample was obtained.

In all the experiments, loading was along the [001] direction of the Al[001]/Si[110] grain family for the textured film and along an arbitrary direction for the non-textured film. To calculate the uncertainty in stress...
measurements, a range of loads were applied on the load cell and the fluctuations in force were recorded over time for each load. Based on the load cell fluctuations, the uncertainty in the calculated stress was less than 10 MPa for all the samples. Similarly, for a prescribed displacement, images of the gauges were recorded over a period of time and analyzed. Based on the analysis, the error in strain measurement was found to be less than 0.003%. There was also an ~10 nm variation in the thickness of both the textured and non-textured film across the wafer. Both the load cell fluctuations and the variation in the film thickness were taken into account for calculating the error in the flow stress of the films.

The Al films were under compressive stress in the as-deposited state and hence the freestanding samples buckled when they were released from the Si substrate. Because the stress for buckling along the length is very low (0.1 MPa) [16], the samples are almost macroscopically stress-free before loading. In addition, to eliminate possible variation in mechanical behavior that can arise from sample size effects, we ensured that all the samples from both the textured and non-textured film had identical dimensions (effective gauge length 375 μm, width 75 μm). Thus, by ensuring uniformity in the fabrication process, mean grain size, and sample dimensions, we were able to isolate the effect of texture on the strain-rate dependent behavior of the Al films.

Fig. 3 shows the stress–strain response of the textured and non-textured film at different strain rates. The corresponding durations of the experiments varied from less than 2 s at the fastest rate to more than 2000 s at the slowest rate. As evident from Fig. 3a, the stress–strain response of the textured film did not vary significantly with strain rate. At all rates, an initial linear response was followed by a gradual increase in flow stress because macroscopic plasticity had set in the samples before 0.9% strain and there was little subsequent strain hardening. Another consideration was that the samples failed around 1% strain at the highest strain rate. For the textured film, the flow stress increased from 302 MPa to 342 MPa (14% increase) as the strain rate increased from 6.9 × 10^{-6}/s to 5.3 × 10^{-3}/s.

In contrast, the non-textured film (Fig. 3b) showed considerable difference in stress–strain response over a similar range of strain rates. Flow stress (σ_{0.9%}) increased from 243 MPa to 473 MPa as the strain rate was increased from 6.8 × 10^{-6}/s to 6.7 × 10^{-3}/s. In addition, during the elastic–plastic transition, the stress–strain slope was significantly higher at the higher strain rates. However, once macroscopic plasticity set in little hardening was observed, irrespective of the strain rate. Thus, while the flow stress was sensitive to the strain rate, the rate of strain hardening was not. To quantitatively compare the stress–strain response of the textured and non-textured films, we calculated the stress hardening exponent (m = d(log(σ))/d(log(ε))) for both the films (Fig. 3c). m for the non-textured film was 0.103, more than six times higher compared to the textured film (m = 0.017).

We note that the Young’s modulus obtained for both the films is less than that of bulk Al (E = 69 GPa). The primary reason for this lower E is that our freestanding samples have a notable curvature (buckling) along the width as well. Thus, the deformation is not uniform during the initial stages of loading and the actual sample cross-section being deformed is smaller than the nominal cross-section assumed for stress calculation. Hence, the stress during the initial phase of loading is underestimated, which results in a lower E. Tensile load–unload experiments on similar Al films indeed show that the modulus obtained from unloading is higher and significantly closer to the bulk value (Supplementary Fig. 1).

Previous studies show that NC and UFG face-centered cubic (FCC) metals exhibit strain rate sensitivities that are an order of magnitude larger than coarse-grained FCC metals, which usually have m of 0.001 to 0.005 [19–21]. UFG Al, for example, has been shown to exhibit m values ranging from 0.02 to 0.2 [22–26] at strain rates comparable to those used in this study. Similarly in NC Al films that undergo discontinuous grain growth, m values ranging from 0.035 to 0.14 have been reported [5].

Typically, m values progressively increase as the grain size is reduced from the microcrystalline to the NC regime [6,27–29]. This grain size dependence has been attributed to the changes in deformation mechanisms that accommodate plasticity [29]. In coarse-grained metals, the rate-controlling process is the cutting of forest dislocations, which results in a low SRS. In contrast, for NC and UFG metals a primary rate-limiting process is the interaction between dislocations and grain boundaries, which serve as obstacles to dislocation motion [30]. Hence, as the density of grain boundaries increases with decreasing grain size, the rate-dependence of deformation behavior becomes more pronounced.

Our results show that UFG metal films with different textures can have considerable differences in SRS, even when their mean grain size and thickness are nearly identical. This suggests that texture plays an
equally important role as grain size in determining the rate sensitivity and deformation mechanisms of UFG metal films.

To obtain insight into the deformation mechanisms that are active in the textured and non-textured films, we performed quasi-static in situ straining experiments on these films in a JEOL 2100F TEM. The experiments were performed under a low intensity, 200 kV electron beam to minimize beam-induced artifacts during in situ TEM deformation [31]. When the textured film began to deform plastically there was notable dislocation activity, and a few grains showed changes in contrast (indicative of out-of-plane grain rotation) when the strain was increased. However, there were no time-dependent changes in grain contrast or motion of bend contours when the strain was held constant (Supplementary Fig. 2). It is worth noting that previous in situ TEM studies of such textured Al films have shown similar results [15,31].

The behavior of the non-textured film, in contrast, was qualitatively different, with a larger fraction of grains showing instantaneous changes in contrast when strain was increased (Fig. 4). More importantly, the grains also underwent gradual changes in contrast over time, often accompanied by motion of bend contours, even when the strain was held constant. Since the grain orientations were continuously changing and most grains were away from the Bragg condition it was difficult to observe dislocation activities in the non-textured film. Nevertheless, the time-dependent grain orientation changes suggest that diffusive relaxation processes could be active in addition to dislocation plasticity.

The strain rate experiments in conjunction with the qualitative in situ TEM experiments point to the following picture of deformation in the textured and non-textured film. In the textured (bicrystalline) film, the initial deformation is relatively homogeneous because elastic modulus for the two sets of grains along their loading directions (<100> and <110>) is quite similar (63.7 GPa and 72.5 GPa, respectively). Thus, the elastic strain mismatch between the grains is small and since they have the same out-of-plane orientation, little or no rotation is required to maintain strain compatibility.

After the initial elastic regime the film undergoes microplastic deformation as relatively larger grains yield first and are followed by progressively smaller grains. However, both sets of grains have sufficient slip systems to accommodate the imposed deformation and all the active slip systems in both sets of grains have the same Schmid factor (\(s = 0.408\)). In effect, plastic anisotropy is nearly eliminated and hence the plastic strain mismatch between the grains is quite small. This again reduces the need for grain rotation to accommodate the deformation.

In contrast, deformation of the non-textured film is considerably more heterogeneous. Because the grains are randomly oriented, there is more variation in elastic modulus (63.7–76 GPa) and hence higher elastic strain mismatch between the grains. More importantly, the Schmid factor of the most favorable slip system in the grains varies from 0.27 (\(s_{min}\)) to 0.5 (\(s_{max}\)). Therefore, plastic anisotropy (\(s_{max}/s_{min}\)) in the non-textured film is significantly more pronounced compared to the textured film. As a result, the plastic strain mismatch between adjoining grains is substantially higher, and the grains need to bend or rotate with respect to each other to maintain strain compatibility.

If the applied strain rate is low, the grains can relax the stress arising from elastic/plastic incompatibility through diffusive processes. But at higher strain rates such relaxation is not possible and thus the macroscopic stress–strain response becomes highly rate sensitive. Note that even though the experiments are performed at room temperature (\(T\)), the homologous temperature (\(T/T_{melting}\)) for Al exceeds 0.3. And since the thin film samples have a large surface to volume ratio, surface diffusion, which has lower activation energy compared to bulk diffusion, can be significant and lead to stress relaxation.

In this context, it is also worth noting that at lower strain rates the non-textured film exhibits lower flow stress than the textured film, whereas the opposite is true at higher strain rates. One possible explanation for this trend is that at lower rates the non-textured film accommodates the deformation through both dislocation plasticity and diffusive processes, which leads to lower stresses compared to the textured film. At higher rates, both the films are likely to accommodate the deformation primarily through dislocation plasticity. And since the grains in the textured film have a relatively high average Schmid factor (\(s = 0.408\)), the flow stress of the textured film is lower compared to the non-textured film.

Overall, the primary finding from our experiments is that the deformation behavior of UFG aluminum films is highly dependent on their texture. The texture-induced changes in deformation mechanisms can introduce substantial changes in strain rate sensitivity, even in films that have nearly identical mean grain sizes and thickness. Thus, it is important to consider both the effect of texture as well as grain size in inferring the deformation mechanisms of UFG metals from strain rate sensitivity measurements.

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Appendix A. Supplementary data

Supplementary data to this article can be found online at http://dx.doi.org/10.1016/j.scriptamat.2015.12.003.
References